Vishay Semiconductors

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Ultrafast Rectifier, 2 x 5 A FRED Pt[®]



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
Package	SMPD (TO-263AC)			
I _{F(AV)}	2 x 5 A			
V _R	600 V			
V _F at I _F	1 V			
t _{rr}	35 ns			
T _J max.	175 °C			
Circuit configuration	Common cathode			

FEATURES

Ultrafast recovery time, reduced Q_{rr}, and soft recovery



COMPLIANT HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM / CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RA	TINGS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage		V _{RRM}		600	V
Average rectified forward current	per device		T _ 152 °C	10	
Average rectilied forward current	per diode	IF(AV)	T _{solder pad} = 153 °C	5	
Non repetitive peak aurge aurgent	per device	1		110	A
Non-repetitive peak surge current	per diode	IFSM	$T_J = 25 \text{ °C}, 6 \text{ ms} \text{ square pulse}$	60	Ī

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-		
Forward voltage, per diode	V _F	I _F = 5 A	-	1.2	1.5	V	
		I _F = 5 A, T _J = 150 °C	-	1	1.25		
Deverse leakage averant ner diade	I _R	$V_{R} = V_{R}$ rated	-	-	3		
Reverse leakage current, per diode		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	150	μA	
Junction capacitance, per diode	CT	V _R = 600 V	-	6	-	pF	

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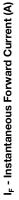


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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	35	-	
Bayaraa raaayar (tima	+	I _F = 0.5 A, I _R = 1 A, I _{rr}	= 0.25 A	-	-	35	ns
Reverse recovery time	t _{rr}	T _J = 25 °C		-	45	-	
		T _J = 125 °C		-	70	-	
Deals reasoning as meant	I _{RRM}	T _J = 25 °C	I _F = 5 A, dI _F /dt = 500 A/μs, V _B = 400 V	-	7	-	Α
Peak recovery current		T _J = 125 °C		-	10	-	A
	0	T _J = 25 °C		-	160	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	370	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C
Thermal resistance, per diode junction to mount	R _{thJM}		-	2.4	3.3	°C/W
Approximate weight				0.55		g
Marking device		Case style SMPD (TO-263AC)		10CI	DU06	



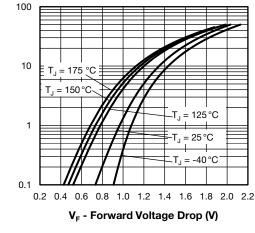


Fig. 1 - Typical Forward Voltage Drop Characteristics

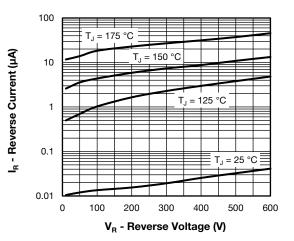


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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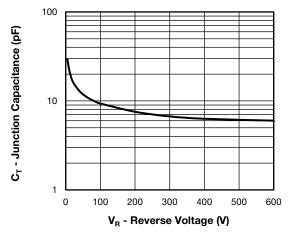


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

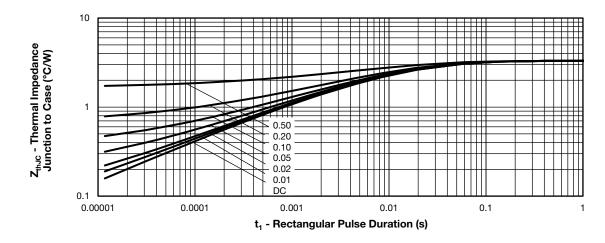
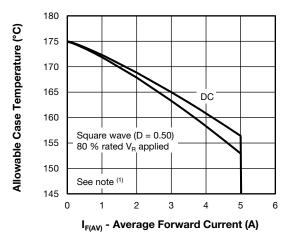
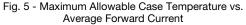


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 5); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

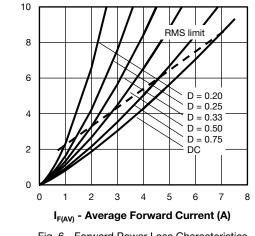


Fig. 6 - Forward Power Loss Characteristics

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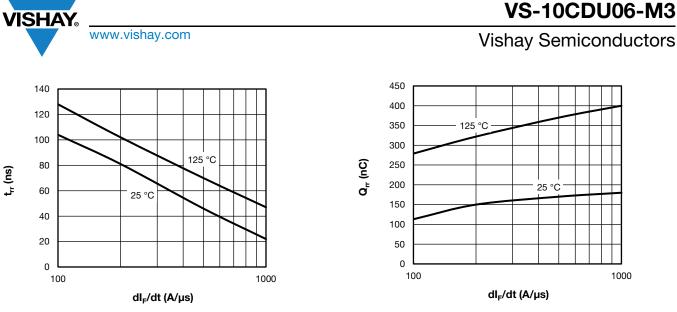


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

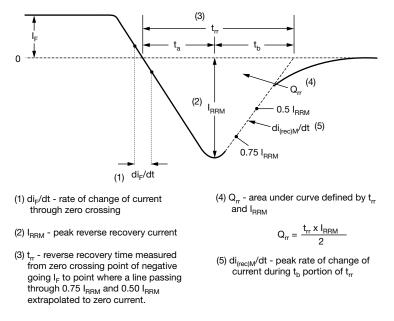


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	10	С	D	U	06	-M3
	•••	10	•		0	00	
	1	2	3	4	5	6	7
	1	- Visl	nay Sem	nicondu	ctors pr	oduct	
	2 ·	- Cur	rent rati	ng (10 A	A)		
	3 ·	- Circ	cuit conf	figuratio	n:		
		C =	commo	on catho	de		
	4	- D =	SMPD	package	Э		
	5	- Pro	cess typ	be,			
		U =	ultrafas	t recove	ery		
	6	- Volt	tage coo	de (06 =	600 V)		
	7	M3	3 = halog	gen-free	e, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPT					
VS-10CDU06-M3/I	2000	2000	13"diameter plastic tape and reel			

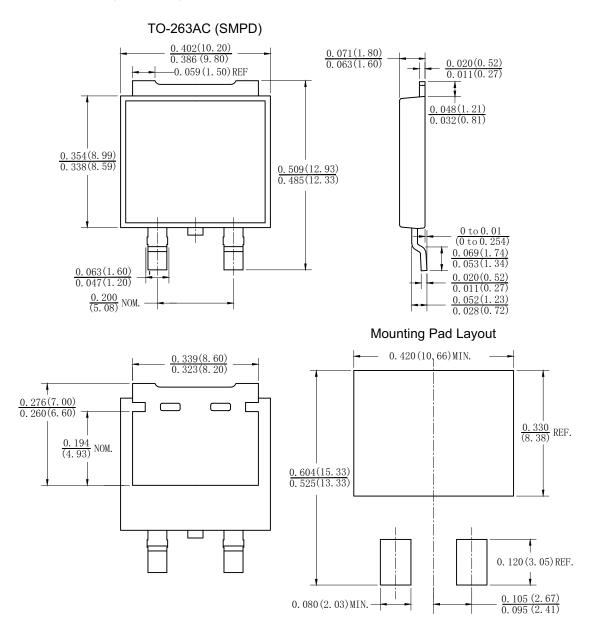
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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